



Progress with multi-cell Nb₃Sn cavity development linked with sample materials characterization

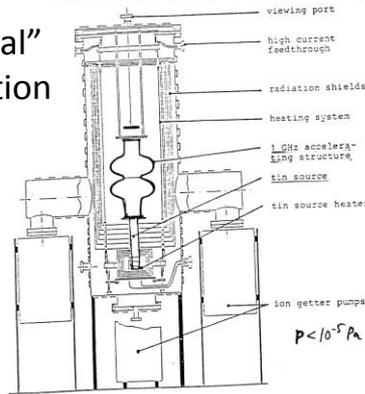
Grigory Ereemeev

Experimental setup

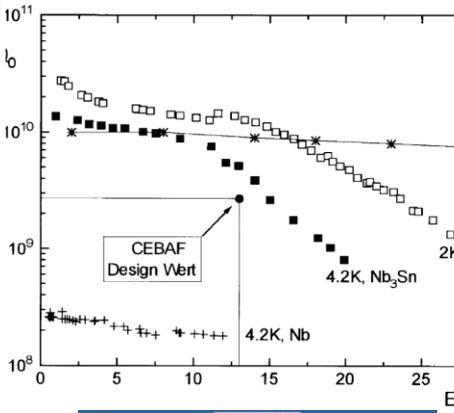
Typical temperature settings to grow Nb₃Sn by vapour diffusion

Fabrication of Nb₃Sn Layers on Bulk Nb Cavities by means of the Vapour Diffusion Technique

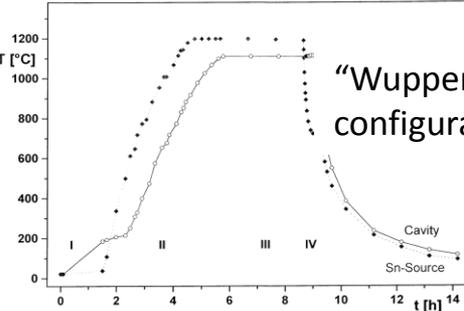
Nb₃Sn coating furnace for accelerator cavities (f≈1GHz, L≈1m) with separate heaters for cavity and Sn source (T≈1200°C)



⇒ Improved nucleation of Nb₃Sn especially on high purity Nb by SnCl₄ (at T≈200°C) and oversaturated Sn pressure (1Pa)

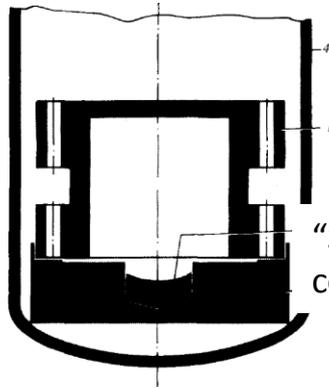


We run "Siemens" configuration



"Wuppertal" configuration

G. Mueller, TESLA 2000-15
G. Müller, P. Kneisel, D. Mansen,
H.Piel, J. Pouryamout, R. W.
Röth, EPAC'96



"Siemens" configuration

l with niobium in the text. G values for growth of Nb₃Sn

times

9.5 GHz @ 1.5 K

polished, n anodized

1.4×10^9	90.5 mT	2.3×10^9	101 mT
4.2×10^5	191	7.5×10^6	37.3
6.8×10^8	70	9.6×10^8	>60
1.0×10^6	100	1.6×10^5	73.3
3.8×10^5	84	1.4×10^5	159
2.9×10^5	84	4×10^5	101
2.7×10^8	5.0×10^8	2.9×10^8	2.9×10^8
2.9×10^7	1.6×10^7	1.6×10^7	1.6×10^7
3.85×10^7	3.0×10^7	3.0×10^7	1.0×10^{16}
2.0×10^7	2.6×10^7	2.6×10^7	159

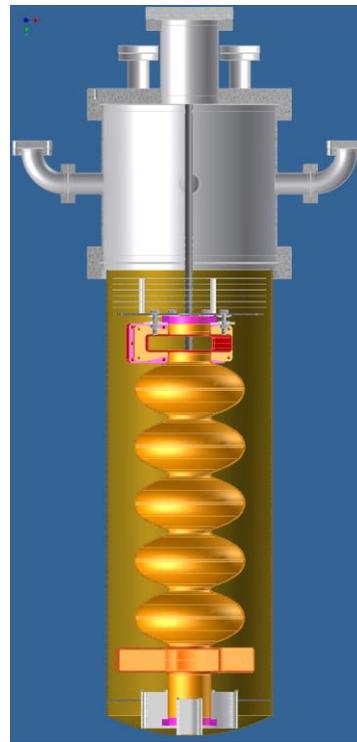
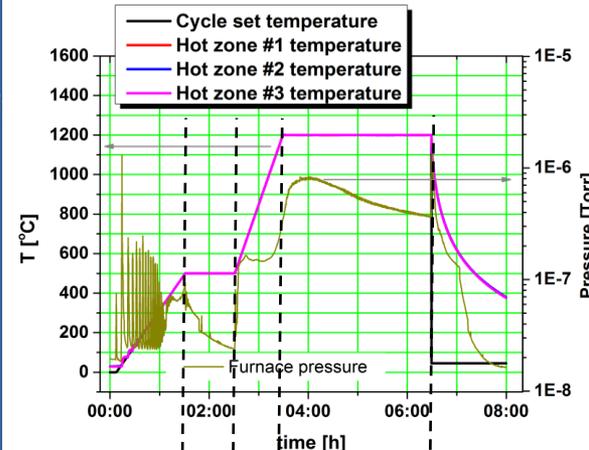


FIG. 1. All-niobium inner reaction room, consisting of the niobium cavity (1) and the niobium bottom plate (2) containing the tin source (3). The lower part of the quartz ampulla (4) is inserted into a resistance furnace.

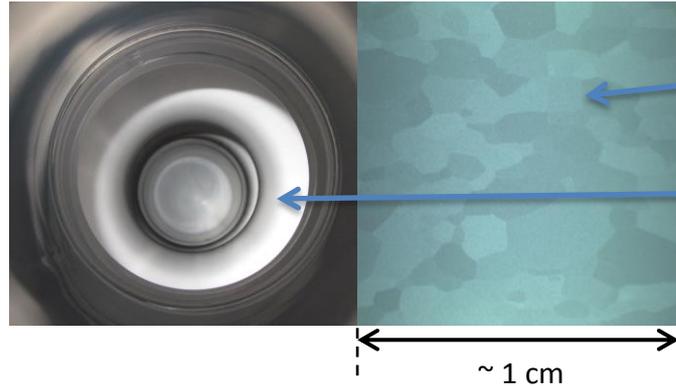
B. Hillenbrand and H. Martens,
J. Appl. Phys. 47, 4151 (1976)



Sn seeding @ 500 °C x 1 hr
Nb₃Sn growth @ 1200 °C x 3 hrs

3 gr of SnCl₂ per cavity, 3 gr of Sn per cell

Cavity experimentation

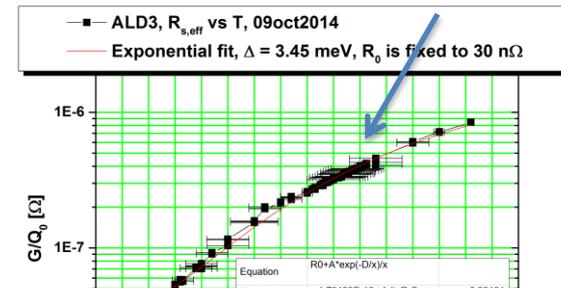


Nb₃Sn on Nb grains

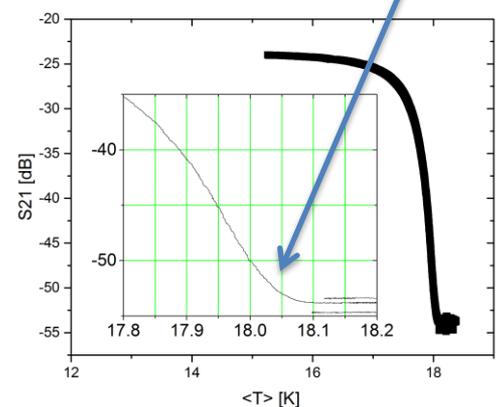
Nb₃Sn coated surface

$\Delta = 3.4$ meV, $\sim 2\times$ larger than that of niobium

~ 1 cm

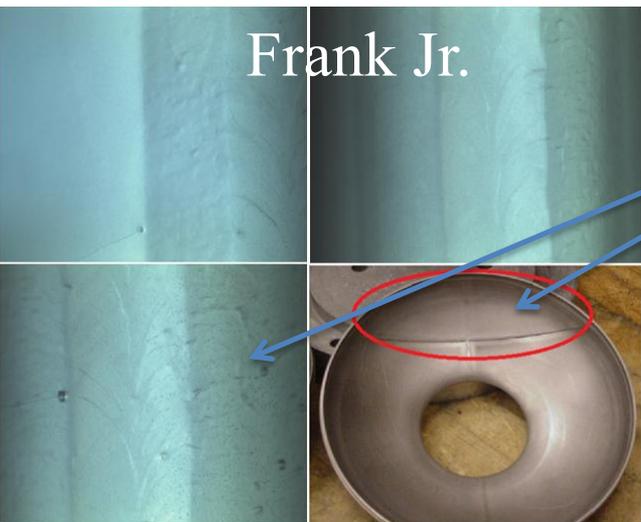


$T_c \approx 18$ K

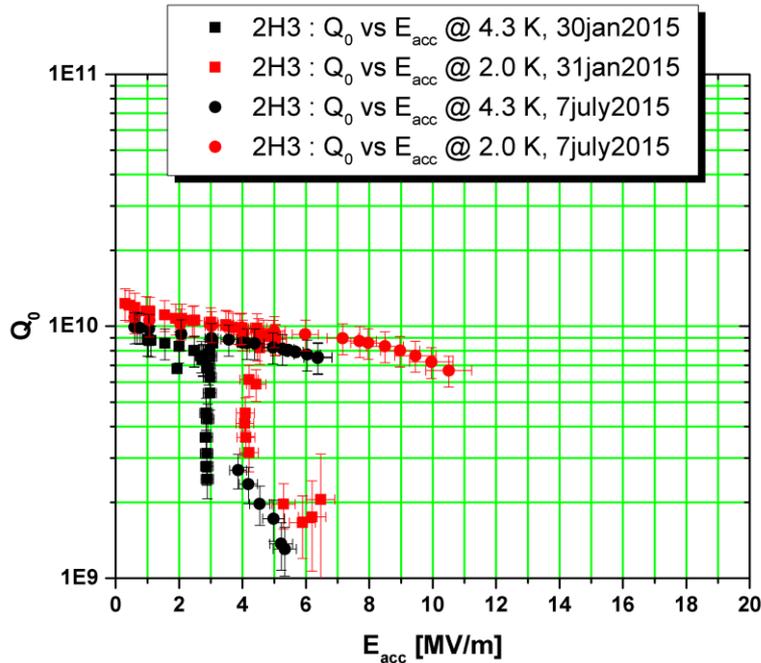


Frank Jr.

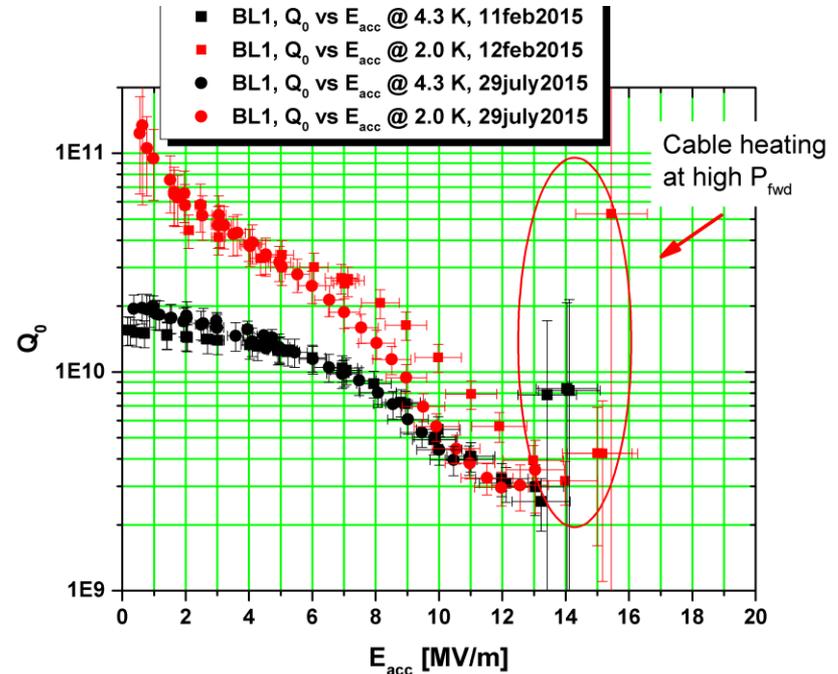
Features were confined to one strip of niobium. The rest of the surface had visually uniform Nb₃Sn coating



Summary of cavity results



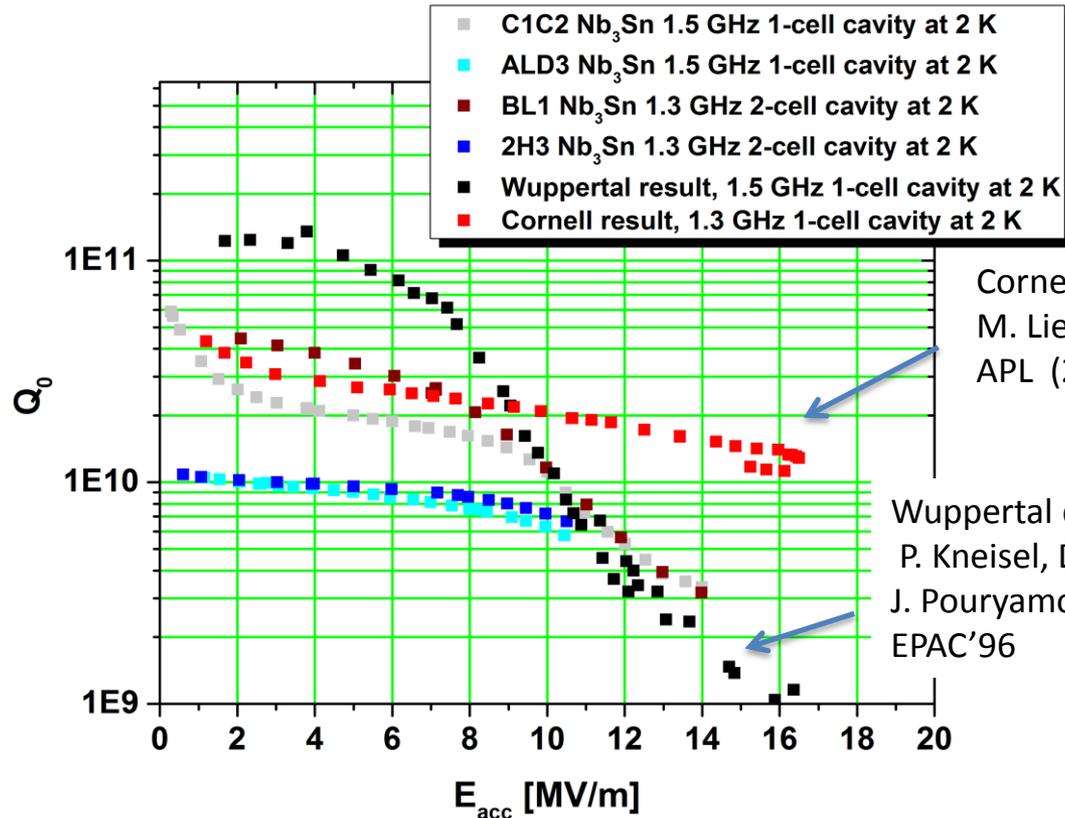
Reproducible Q_0 at 4.3 & 2.0 K after re-coating. Quench gradient improved after 5 μm EP before the second coating.



Reproducible Q_0 at 4.3 & 2.0 K after re-coating. Variation in the Q-slope probably due to FE.

Summary of cavity results

The coating results in $Q_0 \sim 1E10$ below 4.3K for *most* cavities. The cavities are limited by Q_0 degradation and low field quench. Coatings are reproducible for the same cavity.



Cornell data, S. Posen
M. Liepe, and D. L. Hall,
APL (2015)

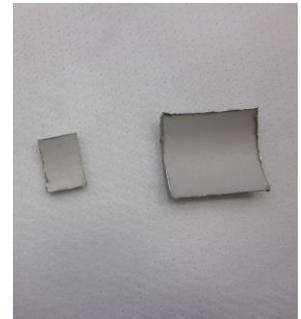
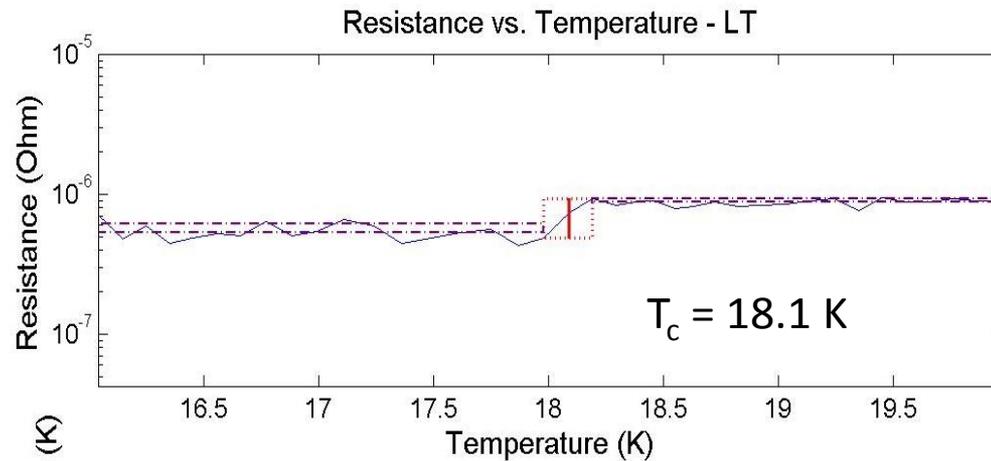
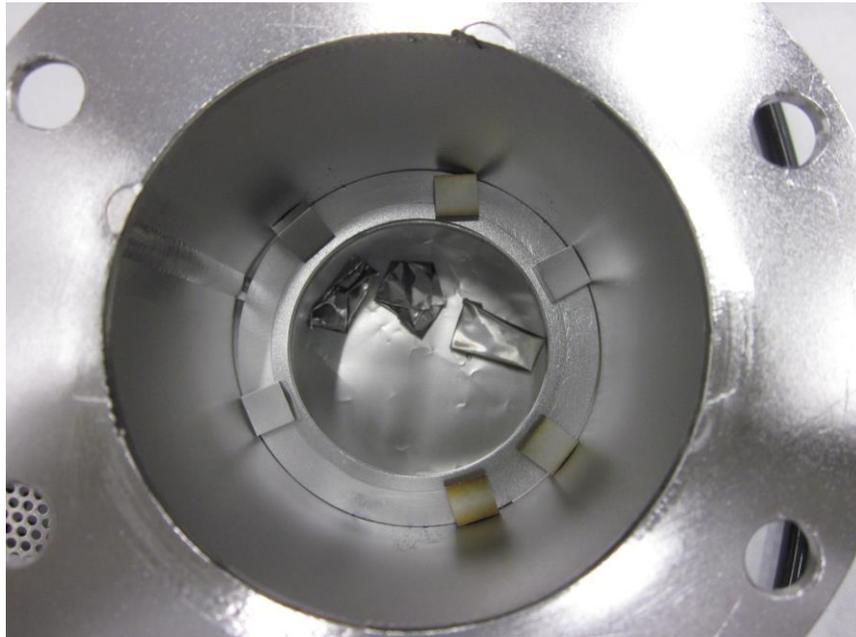
Wuppertal data, G. Müller,
P. Kneisel, D. Mansen, H. Piel,
J. Pouryamout, and R. W. Roth,
EPAC'96

The potential reasons for Q_0 degradation are:

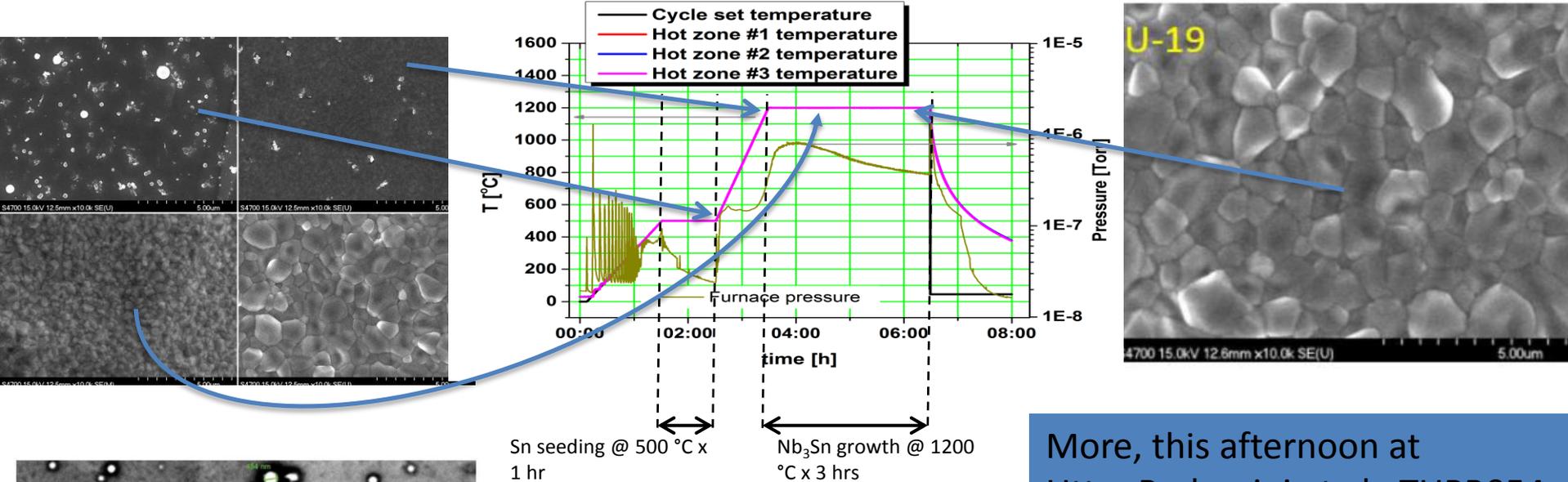
Diffusion driven process -> Sn gradient -> stoichiometry variation?

Cl or Ti contamination?

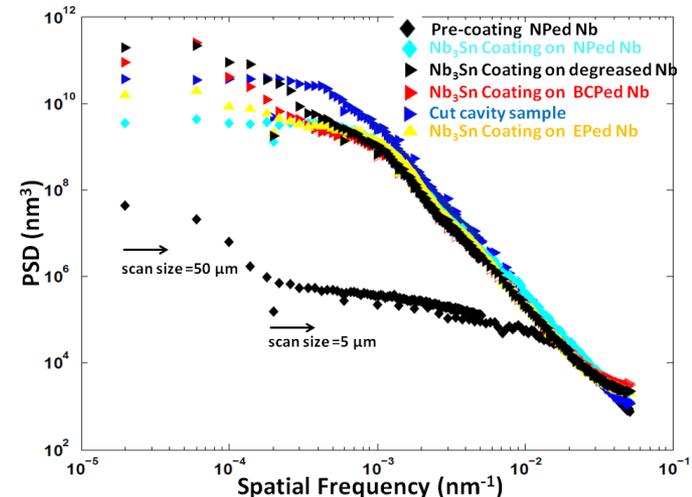
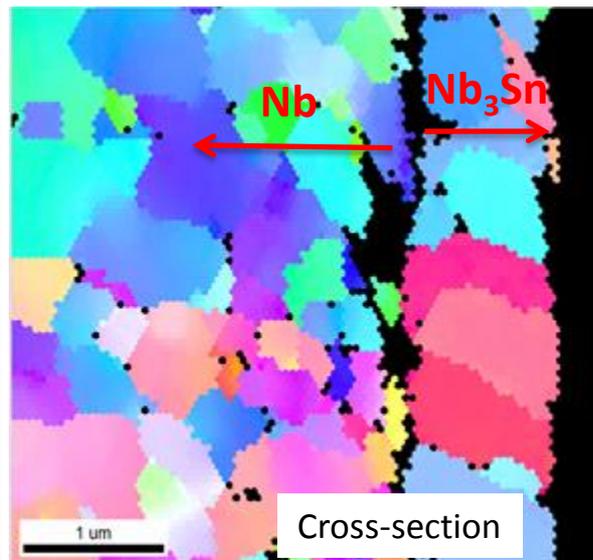
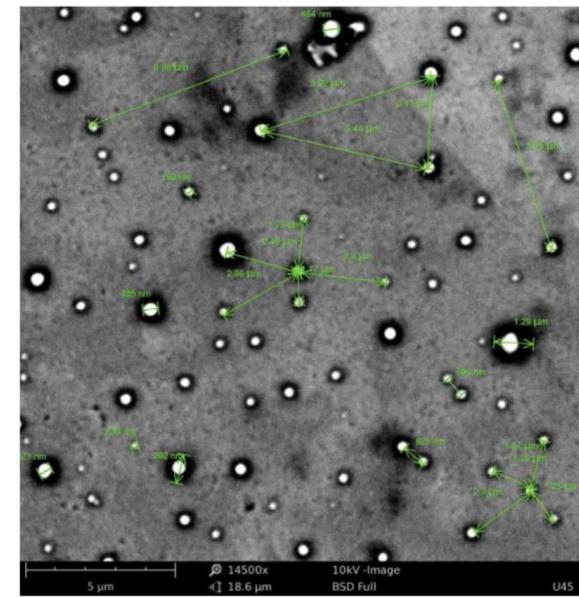
Modelling and analysis approach



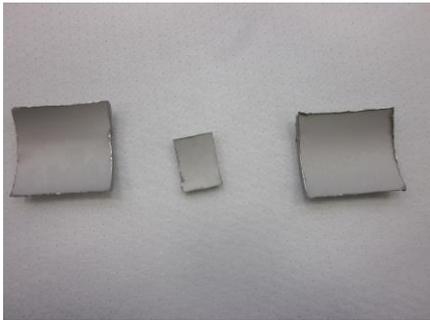
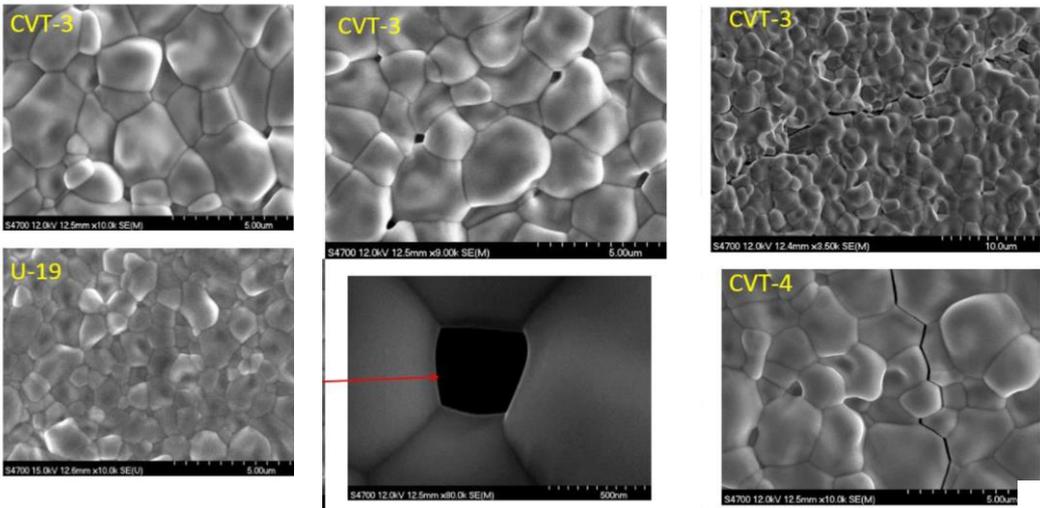
Sample results



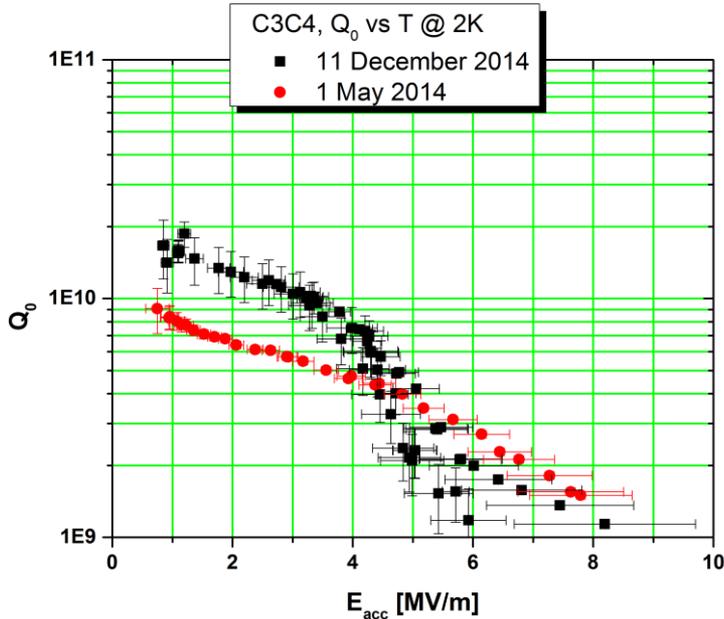
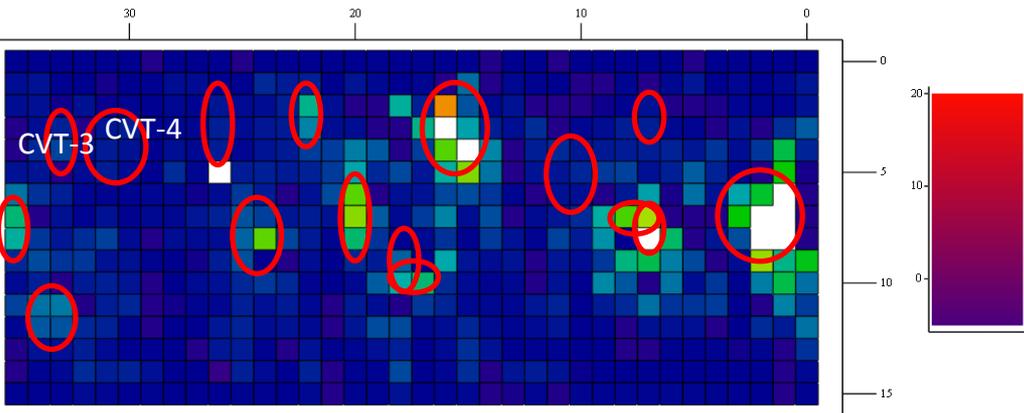
More, this afternoon at
 Uttar Pudasaini et al., TUPB054



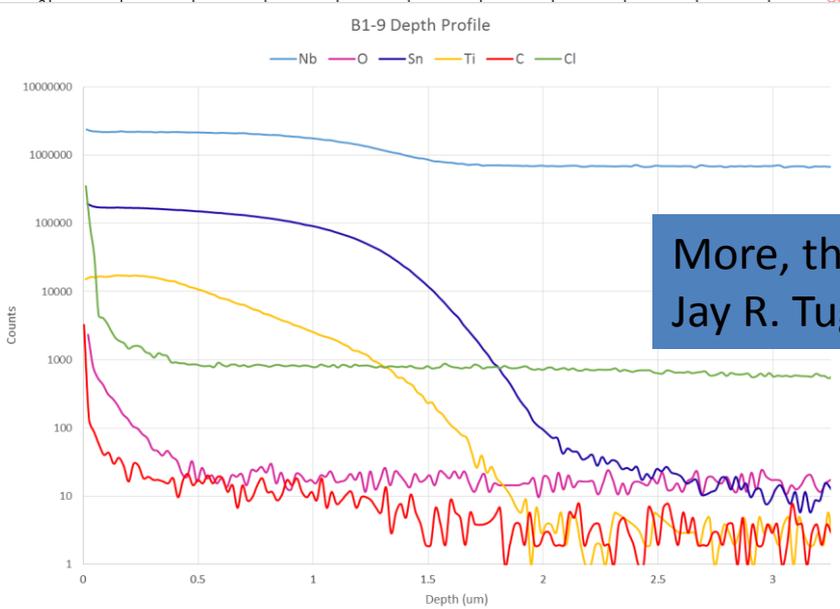
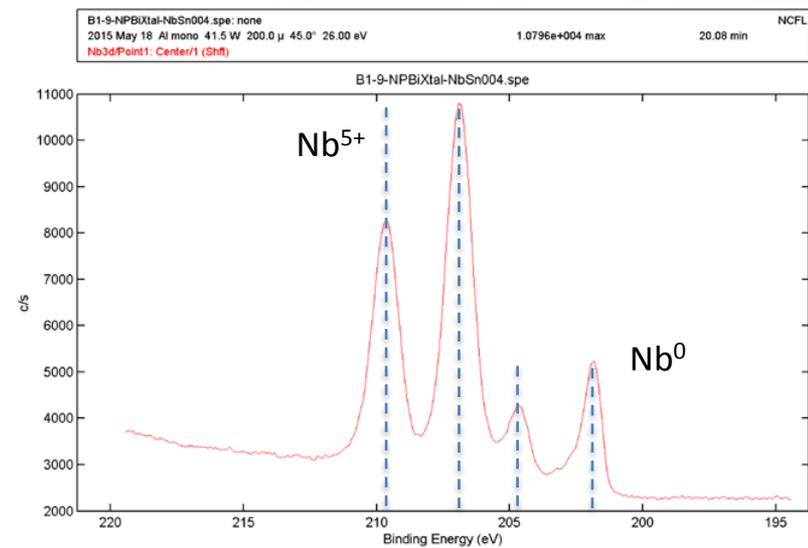
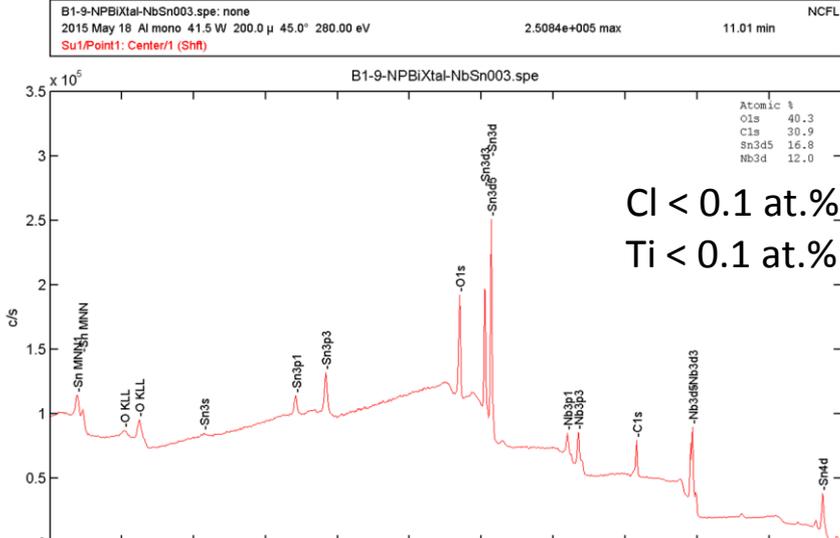
Cutouts results



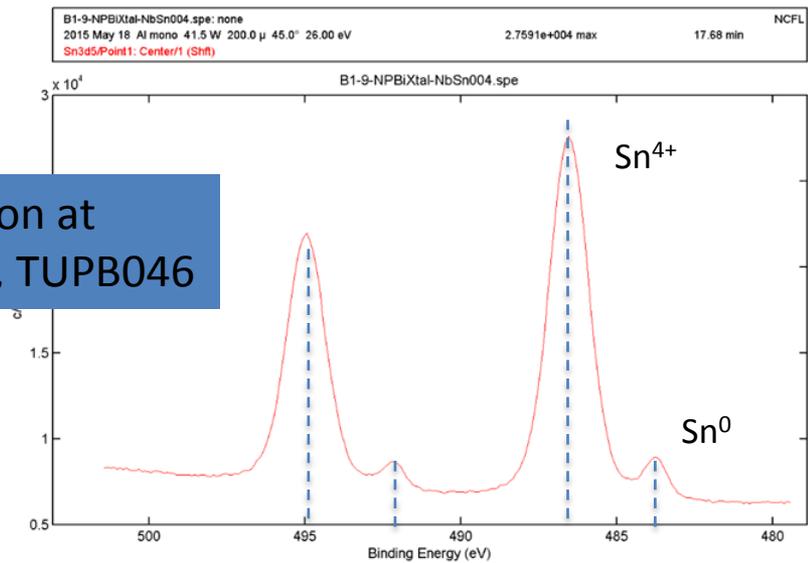
EDS : 24.5 ± 2.0 at. %.



Surface analysis summary



More, this afternoon at
 Jay R. Tuggle et al., TUPB046



Summary and Outlook

Summary:

- Diffusion-based Nb₃Sn coating have been applied to 1-cell 1.5 GHz welded and 2-cell 1.3 GHz seamless cavities.
- The cavities reached up to $E_{acc} = 16$ MV/m limited by strong Q-slope (“Wuppertal” slope) and early quenches.
- The coated Nb₃Sn has the energy gap of about 3.4 meV and the transition temperature of about 18 K consistent with the high quality Nb₃Sn.
- The coating is reproducible for the same cavity, but varies significantly between cavities.
- Surface studies indicate (24.5 ± 2) % Sn content consistent with high quality Nb₃Sn.
- XPS data indicates no gross TI or Cl contamination; a thin layer of Nb₂O₅/SnO₂ on the surface

Outlook:

Coating non-uniformity
Low field quenches
Q-slope
Cryomodule demonstration

Acknowledgements

- Jlab technical staff for assistance with cavity preparation
- Peter Kneisel for the cavities
- Josh Spradlin for sample T_c measurements
- Bill Clemens, Kurt Macha, HyeKyoung Park, Scott Williams, Anne-Marie Valente-Feliciano, and Larry Phillips for valuable suggestions
- Cornell and Fermilab colleagues for useful discussions
- Bob Rimmer for continued support

Co-authors

- Uttar Pudasaini , Jay Tuggle, Michael Kelley, Charlie Reece

More
@
TUPB046 & TUPB054

We are grateful for support from the Office of High Energy Physics, U.S. Department of Energy under grant DE-SC-0014475 to the College of William & Mary.

